

S1112SXU60

Flat Base Rectifier Diode

DS6224-1 February 2018 (LN35119)

FEATURES

- Low losses for high efficiency
- Hermetically sealed for long operational life
- Easily mounted down with 4 M8 bolts on 46mm centres
- Available with flying lead, full and half bar connections on request
- Available anode to base and cathode to base
- Selections available for parallel operation

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
S1112SXU60 to S1112SXU40	6000 to 4000	$V_{RSM} = V_{RRM} + 100V$

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

\$1112\$XU60 for a 6000V anode to base device **\$1112\$XD60** for a 6000V cathode to base device

KEY PARAMETERS

6000V
412A
8500A

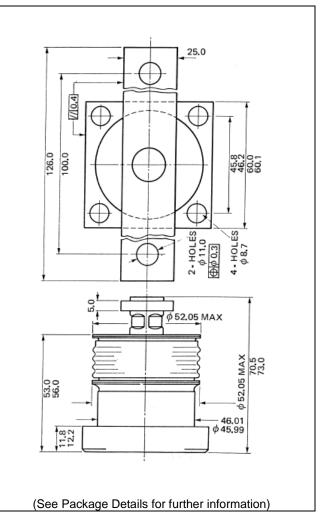


Fig. 1 Package outline

CURRENT RATINGS

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Single Sic	Single Side Cooled (Anode side)					
I _{F(AV)}	Mean forward current	Half wave resistive load	412	А		
I _{F(RMS)}	RMS value	-	648	А		
l _F	Continuous (direct) on-state current	-	532	Α		

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	8.5	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4} \text{ sine}$	0.361	MA ² s

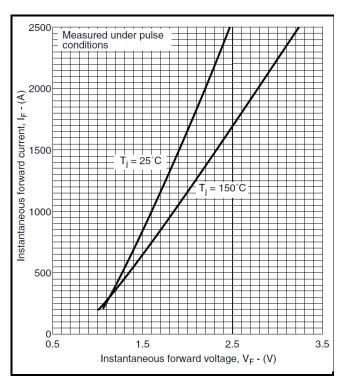
THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to heatsink	dc	-	0.065	°C/W
		Half wave		0.065	°C/W
		3 phase		0.078	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)	ı	150	°C
		Reverse (blocking)	ı	150	°C
T_{stg}	Storage temperature range		-55	165	°C
Torque	Clamping torque		0	22	Nm

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 1800A peak, T _{case} = 150°C	-	2.6	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150°C	-	75	mA
Qs	Total stored charge	I _F = 1000A, dI _{RR} /dt =3A/μs	-	3000	μC
Irr	Peak reverse recovery current	$T_{case} = 150$ °C, $V_R = 100$ V	-	85	Α
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.97	V
r _T	Slope resistance	At T _{vj} = 150°C	-	0.872	mΩ

CURVES



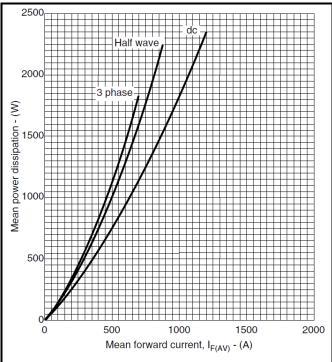
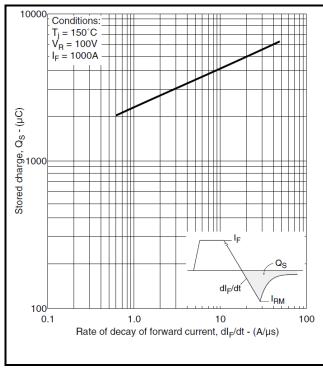


Fig.2 Maximum & minimum on-state characteristics

Fig.3 Dissipation curves



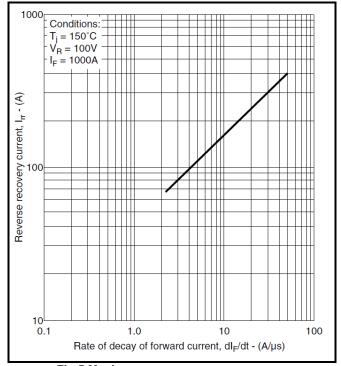
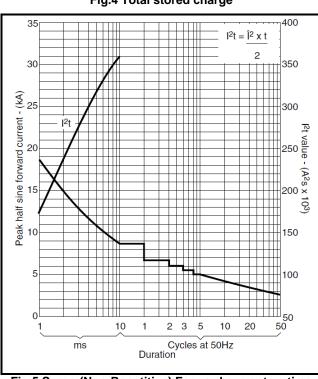


Fig.4 Total stored charge

Fig.5 Maximum reverse recovery current





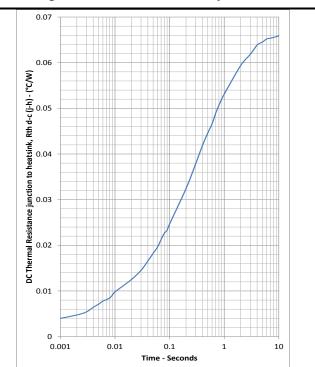
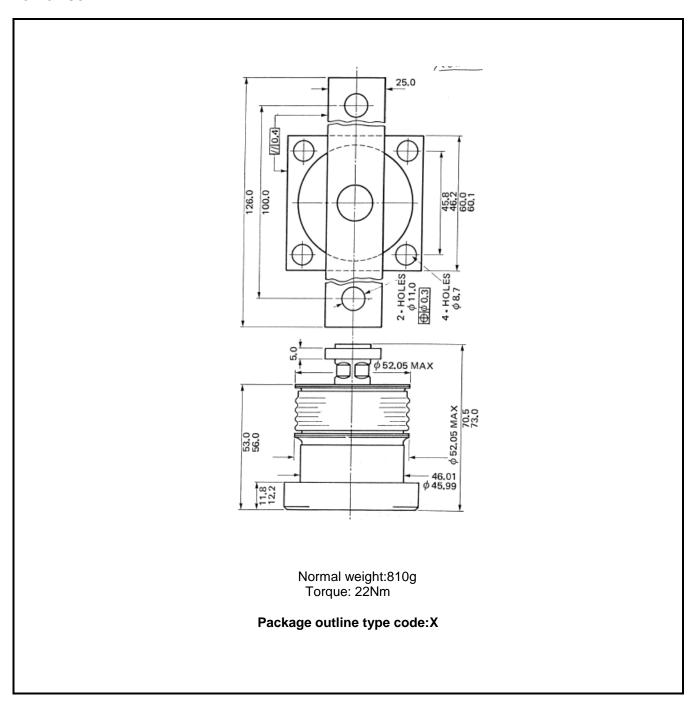


Fig.7 Maximum (limit) transient thermal impedancejunction to heatsink

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.

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No actual design work on the product has been started.

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The product has been approved for production and unless otherwise notified by Dynex any product ordered will be supplied to the **current version of the data sheet prevailing at the**

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